

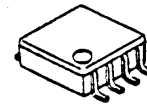
SPDT SWITCH GaAs MMIC

■GENERAL DESCRIPTION

NJG1505R is a GaAs SPDT switch MMIC which features high isolation and low loss and ideally suitable for switching transmit/receiving signal of synthesizer.

This switch is operated in the wide frequency range from 1MHz to 3GHz at low voltage operation from 2.5V with very small VSP8 package.

■PACKAGE OUTLINE

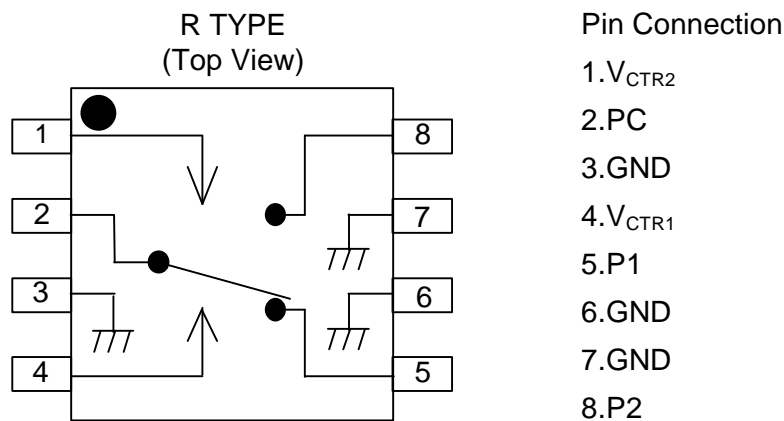


NJG1505R

■FEATURES

- Single and low control voltage +2.5~+5.5V
- High isolation 47dB typ. @f=0.05~1GHz, $P_{in}=0\text{dBm}$
37dB typ. @f=1GHz~2GHz, $P_{in}=0\text{dBm}$
- Low insertion loss 0.6dB typ. @f=1GHz, $P_{in}=0\text{dBm}$
0.8dB typ. @f=2GHz, $P_{in}=0\text{dBm}$
- Low control current 2uA typ. @f=0.05~2.5GHz, $P_{in}=10\text{dBm}$
- Package VSP8 (Mount Size: 4.0x2.9x1.2mm)

■PIN CONFIGURATION



■TRUTH TABLE

“H”= $V_{CTR(H)}$, “L”= $V_{CTR(L)}$

V_{CTR1}	H	L	L	H
V_{CTR2}	L	H	L	H
PC-P1	OFF	ON	-	-
PC-P2	ON	OFF	-	-

NJG1505R

■ABSOLUTE MAXIMUM RATINGS

($T_a=25^{\circ}\text{C}$)

PARAMETER	SYMBOL	RATINGS	UNITS
Input power	P_{in}	27	dBm
Control voltage	V_{CTR}	6	V
Power dissipation	P_D	320	mW
Operating temp.	T_{opr}	-30~+85	$^{\circ}\text{C}$
Storage temp.	T_{stg}	-40~+150	$^{\circ}\text{C}$

■ELECTRICAL CHARACTERISTICS 1

(TEST CIRCUIT 1: $V_{CTR(L)}=0\text{V}$, $V_{CTR(H)}=2.7\text{V}$, $Z_s=Z_o=50\Omega$, $T_a=25^{\circ}\text{C}$)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Control voltage (L)	$V_{CTR(L)}$	$f=0.05\sim 2.5\text{GHz}$, $P_{in}=10\text{dBm}$	-0.2	0	0.2	V
Control voltage (H)	$V_{CTR(H)}$	$f=0.05\sim 2.5\text{GHz}$, $P_{in}=10\text{dBm}$	2.5	2.7	5.5	V
Control current	I_{CTR}	$f=0.05\sim 2.5\text{GHz}$, $P_{in}=10\text{dBm}$	-	2.0	4.0	μA
Isolation 1	ISL1	$f=0.05\sim 1\text{GHz}$, $P_{in}=0\text{dBm}$	40	47	-	dB
Isolation 2	ISL2	$f=1\text{GHz}\sim 2\text{GHz}$, $P_{in}=0\text{dBm}$	33	37	-	dB
Insertion loss 1	LOSS1	$f=1\text{GHz}$, $P_{in}=0\text{dBm}$	-	0.6	1.0	dB
Insertion loss 2	LOSS2	$f=2\text{GHz}$, $P_{in}=0\text{dBm}$	-	0.8	1.2	dB
Pin at 1dB compression point	$P_{-1\text{dB}}$	$f=2\text{GHz}$	19	22	-	dBm
VSWR	VSWR	$f=0.05\sim 2.5\text{GHz}$, ON STATE	-	1.5	1.8	
Switching time	T_{SW}	$f=0.05\sim 2.5\text{GHz}$	-	8	-	ns

■ELECTRICAL CHARACTERISTICS 2

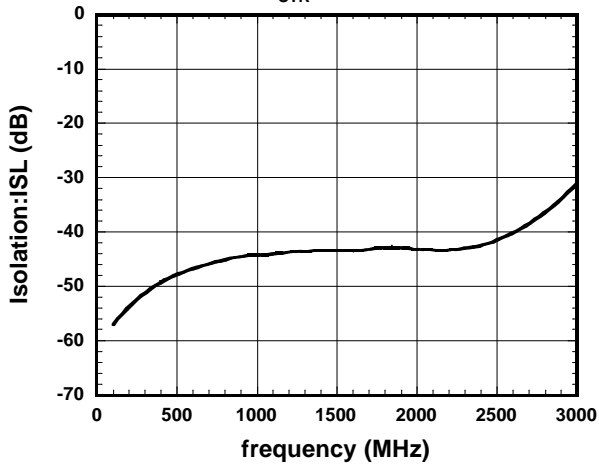
(TEST CIRCUIT 2: $V_{CTR(L)}=0\text{V}$, $V_{CTR(H)}=2.7\text{V}$, $Z_s=Z_o=50\Omega$, $T_a=25^{\circ}\text{C}$)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Isolation 3	ISL3	$f=1\sim 100\text{MHz}$, $P_{in}=0\text{dBm}$	-	55	-	dB
Insertion loss 3	LOSS3	$f=1\sim 100\text{MHz}$, $P_{in}=0\text{dBm}$	-	0.5	-	dB

■ TYPICAL CHARACTERISTICS

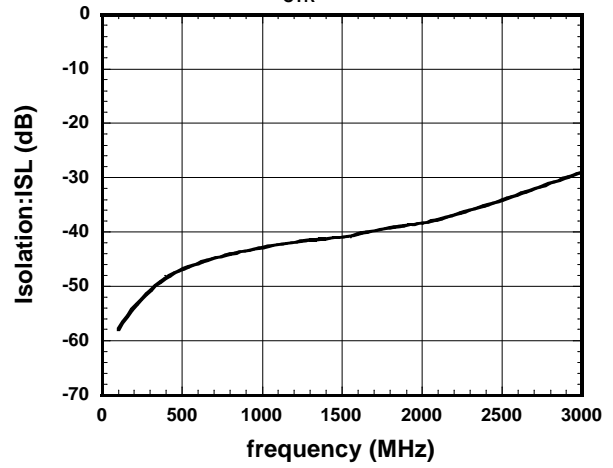
PC-P1 Isolation

($V_{CTR} = 0V/2.7V$)



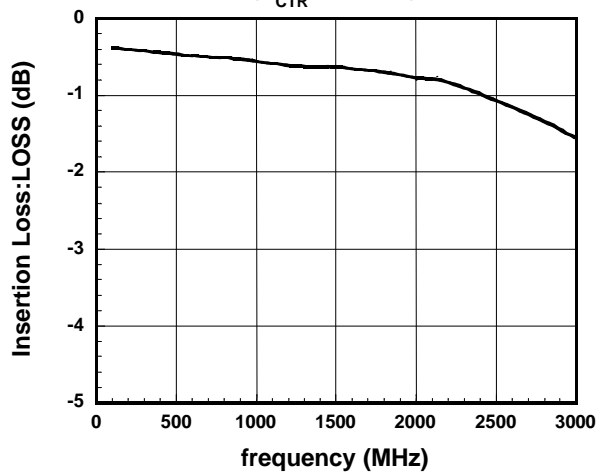
PC-P2 Isolation

($V_{CTR} = 0V/2.7V$)



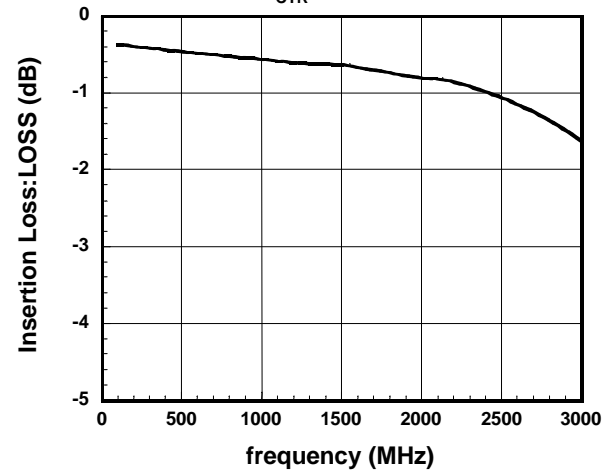
PC-P1 Insertion Loss

0.1-3GHz
($V_{CTR} = 0V/2.7V$)



PC-P2 Insertion Loss

0.1-3GHz
($V_{CTR} = 0V/2.7V$)

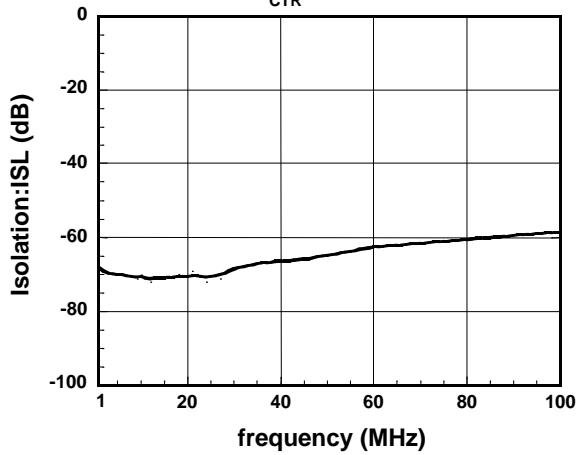


NJG1505R

■ TYPICAL CHARACTERISTICS

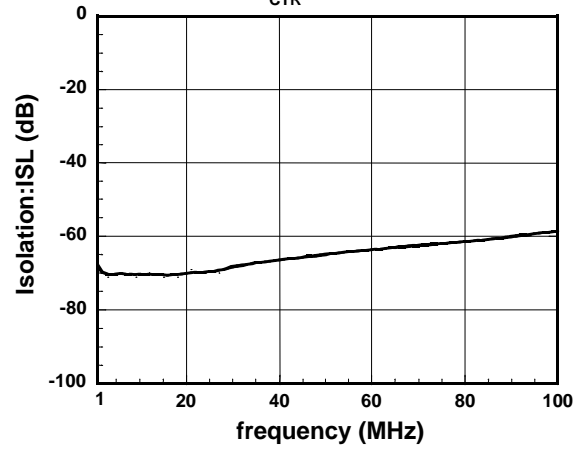
PC-P1 Isolation

1-100MHz
($V_{CTR}=0V/2.7V$)



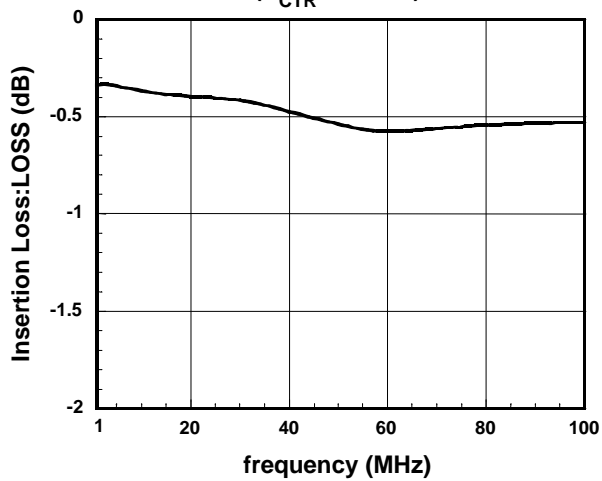
PC-P2 Isolation

1-100MHz
($V_{CTR}=0V/2.7V$)



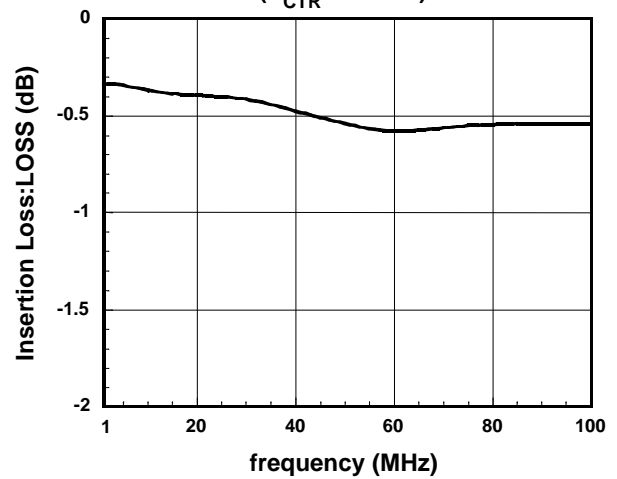
PC-P1 Insertion Loss

1-100MHz
($V_{CTR}=0V/2.7V$)



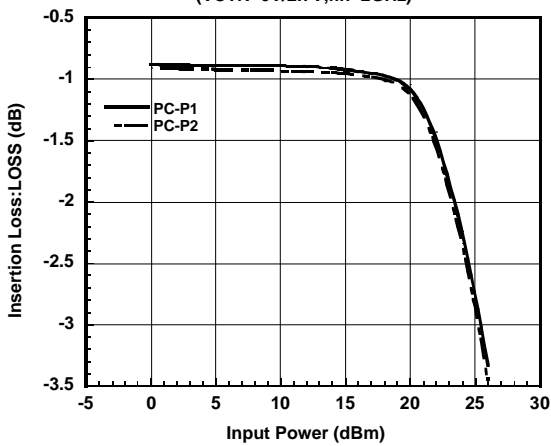
PC-P2 Insertion Loss

1-100MHz
($V_{CTR}=0V/2.7V$)

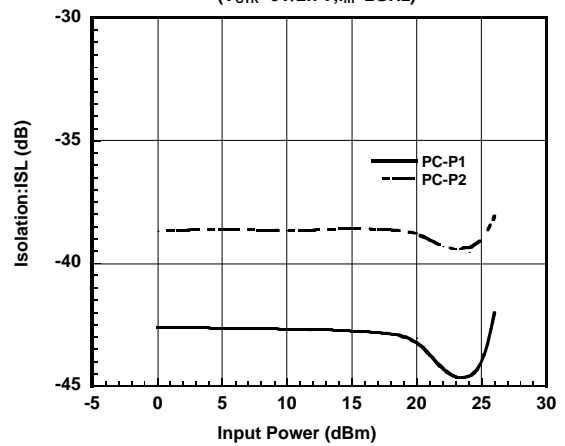


TYPICAL CHARACTERISTICS

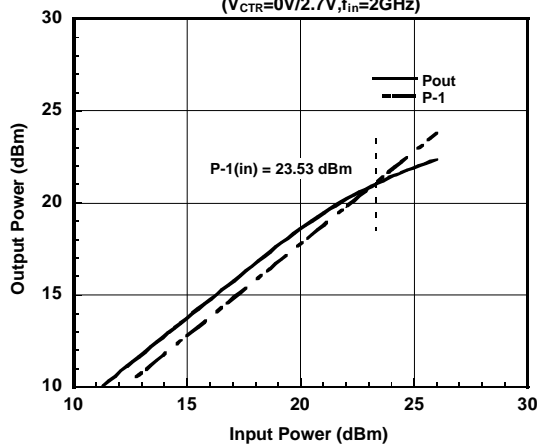
Insertion Loss vs. Input Power ($V_{CTR}=0V/2.7V, f_{in}=2GHz$)



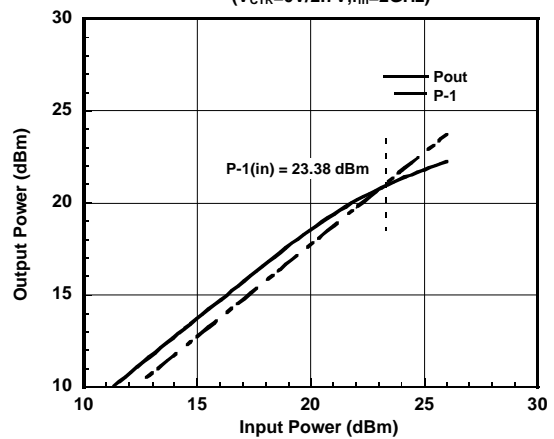
Isolation vs. Input Power ($V_{CTR}=0V/2.7V, f_{in}=2GHz$)



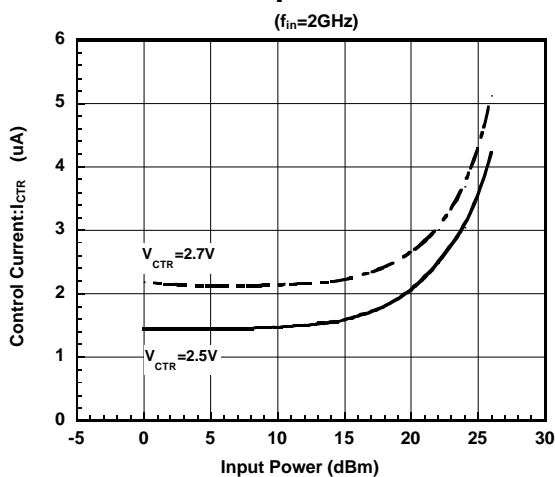
(PC-P1) Output Power vs. Input Power ($V_{CTR}=0V/2.7V, f_{in}=2GHz$)



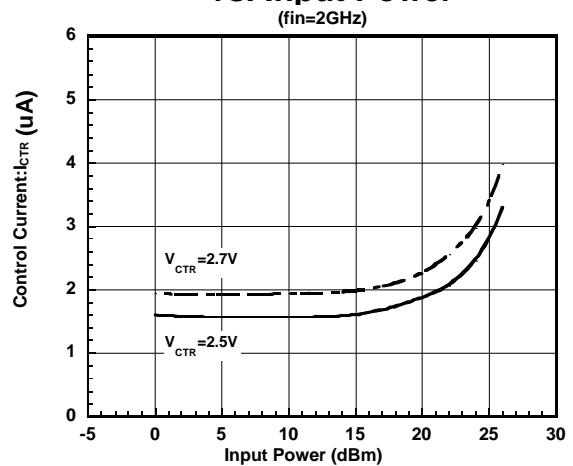
(PC-P2) Output Power vs. Input Power ($V_{CTR}=0V/2.7V, f_{in}=2GHz$)



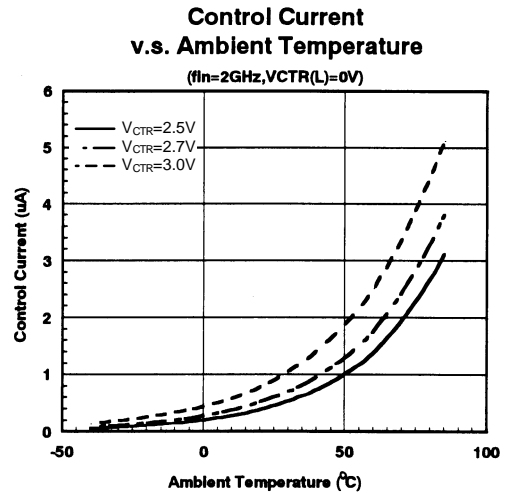
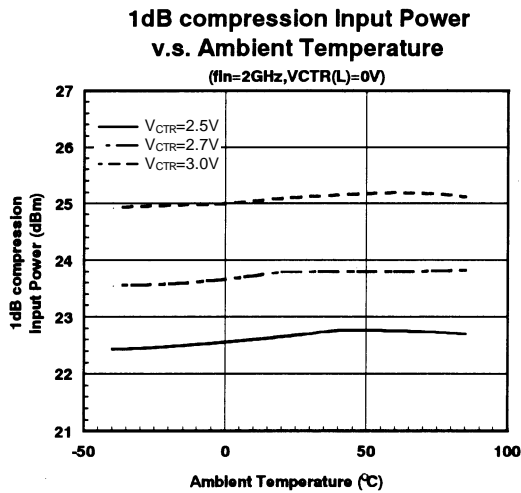
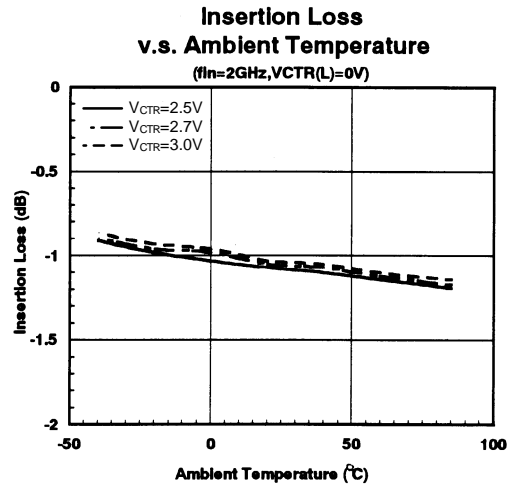
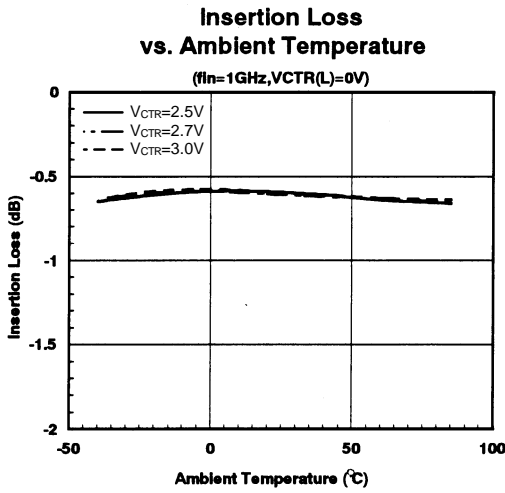
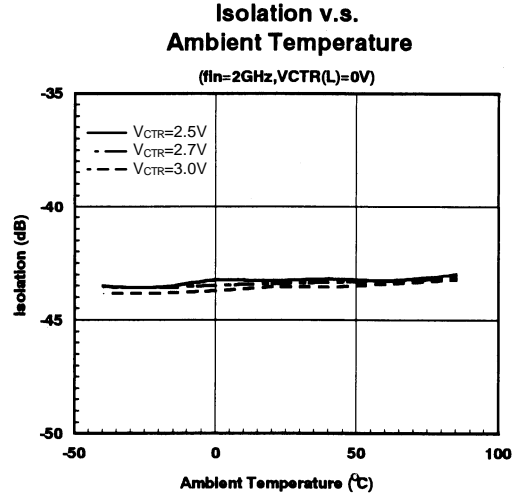
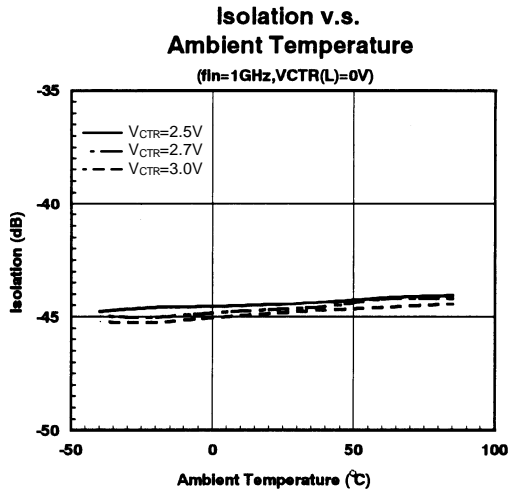
(PC-P1) Control Current vs. Input Power ($f_{in}=2GHz$)



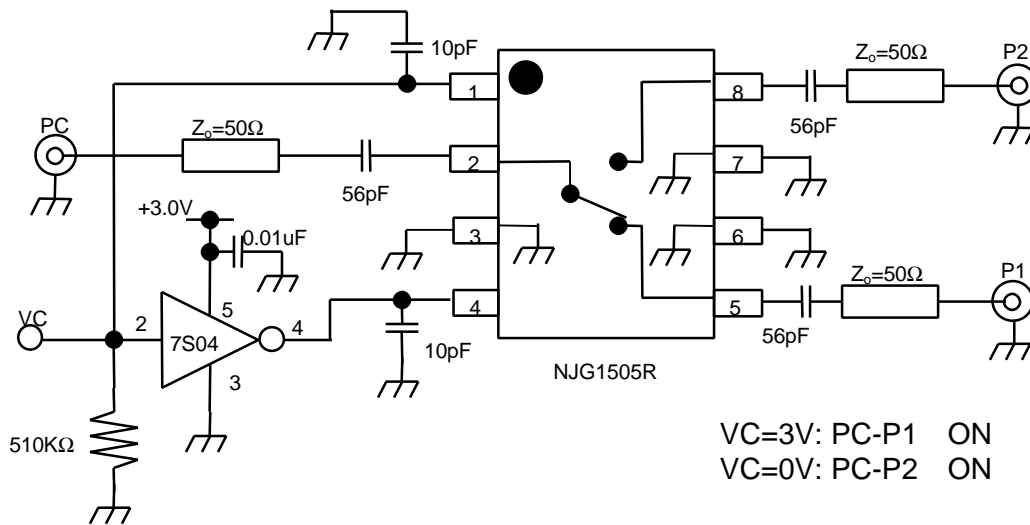
(PC-P2) Control Current vs. Input Power ($f_{in}=2GHz$)



TYPICAL CHARACTERISTICS

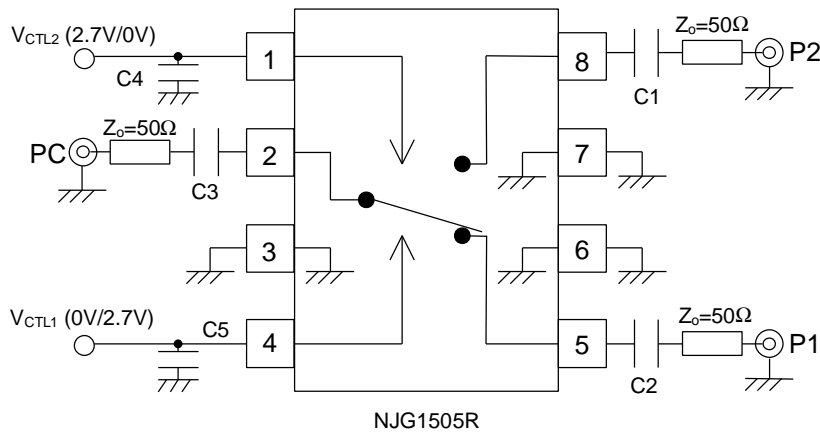


■APPLICATION CIRCUIT: Single control signal operation by using C-MOS inverter.



- [1] Please connect bypass capacitors to the supply terminals of the C-MOS inverter.
- [2] In order to stabilize input impedance of inverter, please pull down using 510KΩ resistor from the input terminal of the C-MOS inverter to the ground plane.

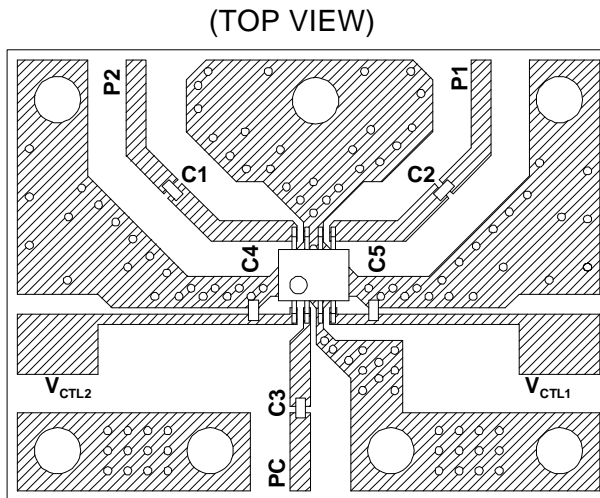
■TEST CIRCUIT



	Test circuit 1 0.5~2GHz	Test circuit 2 1~500MHz
C1~C3	56pF	0.1uF
C4, C5	10pF	1000pF

NJG1505R

RECOMMENDED PCB DESIGN



PCB SIZE=30.0x22.5mm

PCB: FR-4, t=0.5mm

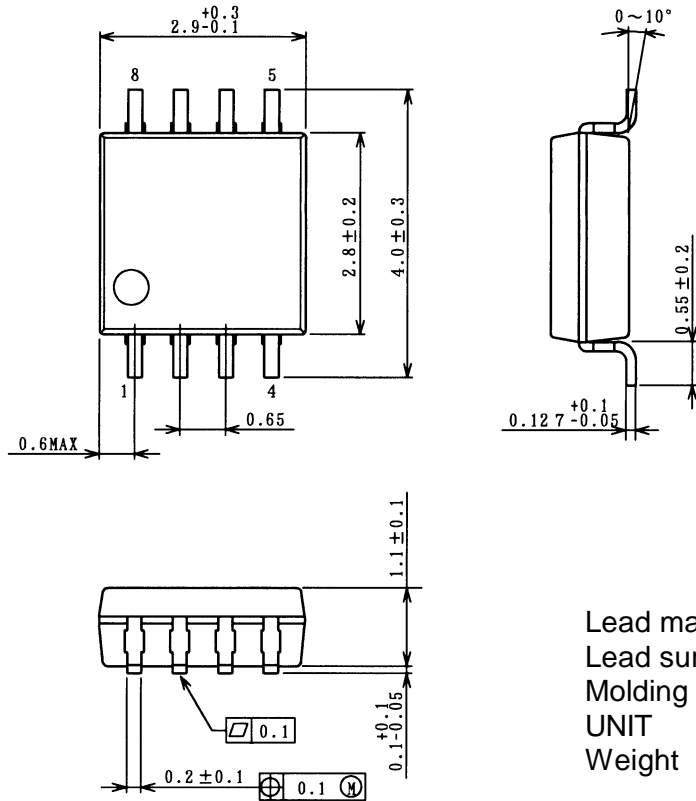
STRIPLINE WIDTH=1mm

CAPACITORS: size 1005

Precautions

- [1] External capacitors should be connected to the input and output RF terminals (P1, P2, PC) to block the DC current. The values of these capacitors depend on RF frequency range. Please use a 0.01uF capacitor at 50 to 100MHz, a 0.1uF capacitor at 100 to 500MHz, and a 56pF capacitor at 500MHz to 2GHz.
- [2] Decoupling capacitors should be connected to the control terminals (V_{CTR1} , V_{CTR2}) as close as possible. The values of these capacitors should be selected to 0.01uF at 50 to 100MHz, 0.1uF at 100 to 500MHz, and 10pF at 500MHz to 2GHz. Please take care to select these values because the capacitors make switching time long.
- [3] In order to keep good isolation characteristics, the ground terminals (3, 6, 7 pin) should be connected to ground pattern with wider width as close as possible, and through-hole in the ground plane should also be placed as close as possible.
- [4] The isolation of PC port to P1 port is greater than the isolation of PC port to P2 port. Please consider this information to create better isolation design.

PACKAGE OUTLINE (VSP8)



Lead material	: Copper
Lead surface finish	: Solder plating
Molding material	: Epoxy resin
UNIT	: mm
Weight	: 22mg

Cautions on using this product

This product contains Gallium-Arsenide (GaAs) which is a harmful material.

- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

[CAUTION]

The specifications on this databook are only given for information, without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.